

74AHC157; 74AHCT157

Quad 2-input multiplexer

Product data sheet

1. General description

The 74AHC/AHCT157 are high-speed Si-gate CMOS devices and are pin compatible with Low Power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74AHC/AHCT157 are quad 2-input multiplexer which select 4 bits of data from two sources under the control of a common data select input (S). The enable input ($\bar{E}$) is active LOW. When $\bar{E}$ is HIGH, all of the outputs (1Y to 4Y) are forced LOW regardless of all other input conditions.

Moving the data from two groups of registers to four common output buses is a common use of the 74AHC/AHCT157. The state of the common data select input (S) determines the particular register from which the data comes. It can also be used as function generator. The device is useful for implementing highly irregular logic by generating any four of the 16 different functions of two variables with one variable common. The 74AHC/AHCT157 is logic implementation of a 4-pole, 2-position switch, where the position of the switch is determined by the logic levels applied to S.

The logic equations are:

$$1Y = \bar{E} \times (1I1 \times S + 1I0 \times \bar{S})$$

$$2Y = \bar{E} \times (2I1 \times S + 2I0 \times \bar{S})$$

$$3Y = \bar{E} \times (3I1 \times S + 3I0 \times \bar{S})$$

$$4Y = \bar{E} \times (4I1 \times S + 4I0 \times \bar{S})$$

The 74AHC/AHCT157 is identical to the 74AHC/AHCT158 but has non-inverting (true) outputs.

2. Features

- Balanced propagation delays
- All inputs have a Schmitt-trigger action
- Inputs accept voltages higher than V_{CC}
- Multiple input enable for easy expansion
- Ideal for memory chip select decoding
- For 74AHC157 only: operates with CMOS input levels
- For 74AHCT157 only: operates with TTL input levels
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101C exceeds 1000 V

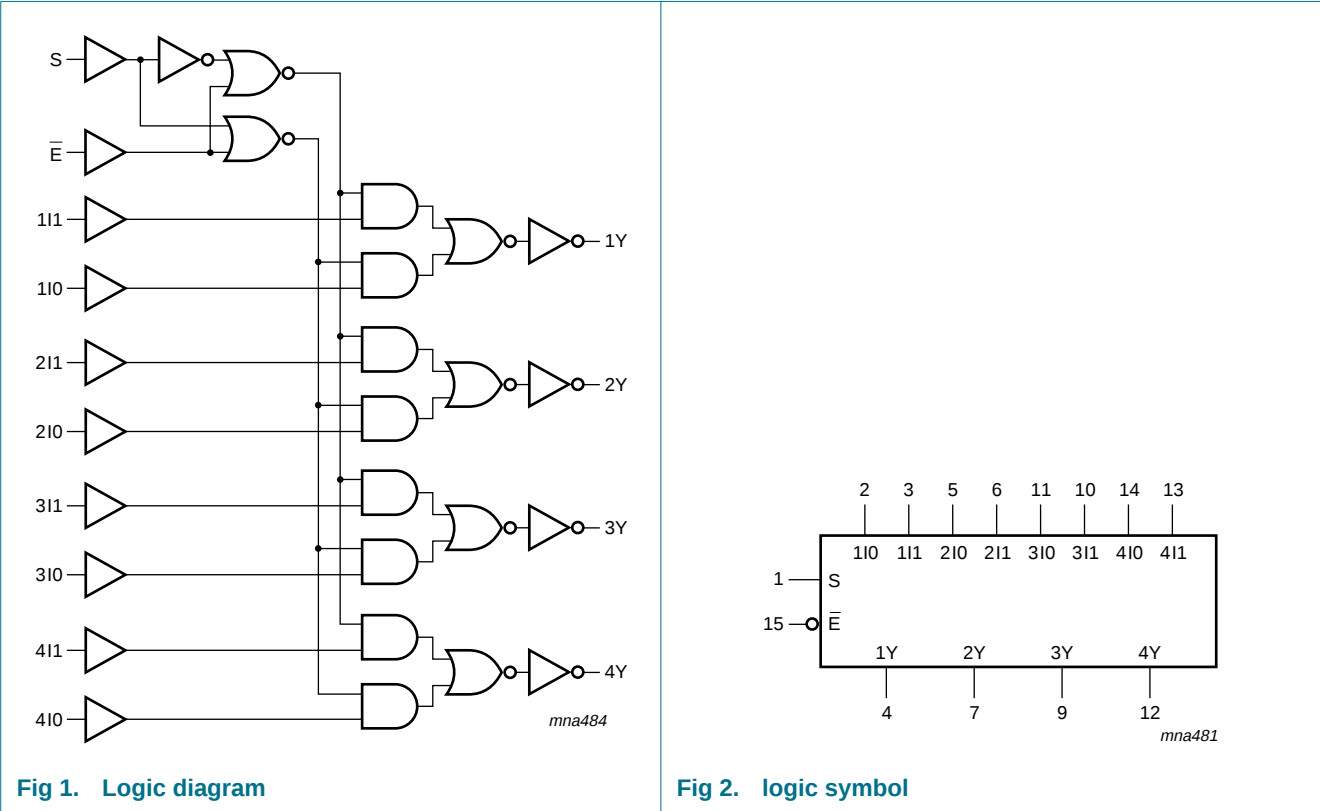
- Multiple package options
- Specified from −40 °C to +85 °C and from −40 °C to +125 °C

3. Ordering information

Table 1. Ordering information

Type number	Package			Version
	Temperature range	Name	Description	
74AHC157D	−40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74AHCT157D				
74AHC157PW	−40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74AHCT157PW				
74AHC157BQ	−40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm	SOT763-1
74AHCT157BQ				

4. Functional diagram



7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
V_I	input voltage		-0.5	+7.0	V
I_{IK}	input clamping current	$V_I < -0.5$ V	[1] -20	-	mA
I_{OK}	output clamping current	$V_O < -0.5$ V or $V_O > V_{CC} + 0.5$ V	[1] -	±20	mA
I_O	output current	$V_O = -0.5$ V to $(V_{CC} + 0.5$ V)	-	±25	mA
I_{CC}	supply current		-	75	mA
I_{GND}	ground current		-75	-	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	$T_{amb} = -40$ °C to +125 °C			
	SO16 package		[2] -	500	mW
	TSSOP16 package		[3] -	500	mW
	DHVQFN16 package		[4] -	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] P_{tot} derates linearly with 8 mW/K above 70 °C.

[3] P_{tot} derates linearly with 5.5 mW/K above 60 °C.

[4] P_{tot} derates linearly with 4.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74AHC157			74AHCT157			Unit
			Min	Typ	Max	Min	Typ	Max	
V_{CC}	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
V_I	input voltage		0	-	5.5	0	-	5.5	V
V_O	output voltage		0	-	V_{CC}	0	-	V_{CC}	V
T_{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 3.3$ V ± 0.3 V	-	-	100	-	-	-	ns/V
		$V_{CC} = 5.0$ V ± 0.5 V	-	-	20	-	-	20	ns/V

9. Static characteristics

Table 6. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	25 °C			–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
For type 74AHC157										
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
		V _{CC} = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V _{CC} = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
		V _{CC} = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V _{CC} = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}								
		I _O = –50 µA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = –50 µA; V _{CC} = 3.0 V	2.9	3.0	-	2.9	-	2.9	-	V
		I _O = –50 µA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = –4.0 mA; V _{CC} = 3.0 V	2.58	-	-	2.48	-	2.40	-	V
		I _O = –8.0 mA; V _{CC} = 4.5 V	3.94	-	-	3.8	-	3.70	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}								
		I _O = 50 µA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 50 µA; V _{CC} = 3.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 50 µA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.36	-	0.44	-	0.55	V
		I _O = 8.0 mA; V _{CC} = 4.5 V	-	-	0.36	-	0.44	-	0.55	V
I _I	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	µA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 5.5 V	-	-	4.0	-	40	-	80	µA
C _I	input capacitance		-	3.0	10	-	10	-	10	pF
C _O	output capacitance		-	4.0	-	-	-	-	-	pF
For type 74AHCT157										
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL} ; V _{CC} = 4.5 V								
		I _O = –50 µA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = –8.0 mA	3.94	-	-	3.8	-	3.70	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL} ; V _{CC} = 4.5 V								
		I _O = 50 µA	-	0	0.1	-	0.1	-	0.1	V
		I _O = 8.0 mA	-	-	0.36	-	0.44	-	0.55	V

Table 6. Static characteristics ...continued
 Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	25 °C			–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
I_I	input leakage current	$V_I = 5.5 \text{ V}$ or GND; $V_{CC} = 0 \text{ V}$ to 5.5 V	-	-	0.1	-	1.0	-	2.0	μA
I_{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0 \text{ A}$; $V_{CC} = 5.5 \text{ V}$	-	-	4.0	-	40	-	80	μA
ΔI_{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$; $I_O = 0 \text{ A}$; other pins at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V	-	-	1.35	-	1.5	-	1.5	mA
C_I	input capacitance		-	3	10	-	10	-	10	pF
C_O	output capacitance		-	4.0	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics
 GND = 0 V; For test circuit see [Figure 9](#).

Symbol	Parameter	Conditions	25 °C			–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	Min	Max	

For type 74AHC157

t_{pd}	propagation delay	nI0, nI1 to nY; see Figure 7 ^[2]								
		$V_{CC} = 3.0 \text{ V}$ to 3.6 V								
		$C_L = 15 \text{ pF}$	-	4.4	9.7	1.0	11.5	1.0	12.5	ns
		$C_L = 50 \text{ pF}$	-	6.3	13.2	1.0	15.0	1.0	16.5	ns
		$V_{CC} = 4.5 \text{ V}$ to 5.5 V								
		$C_L = 15 \text{ pF}$	-	3.2	6.4	1.0	7.5	1.0	8.0	ns
		$C_L = 50 \text{ pF}$	-	4.6	8.4	1.0	9.5	1.0	10.5	ns
		S to nY; see Figure 7 ^[2]								
		$V_{CC} = 3.0 \text{ V}$ to 3.6 V								
		$C_L = 15 \text{ pF}$	-	4.8	13.6	1.0	16.0	1.0	17.0	ns
		$C_L = 50 \text{ pF}$	-	6.8	17.1	1.0	19.5	1.0	21.5	ns
		$V_{CC} = 4.5 \text{ V}$ to 5.5 V								
		$C_L = 15 \text{ pF}$	-	3.6	8.6	1.0	10.0	1.0	11.0	ns
		$C_L = 50 \text{ pF}$	-	5.2	10.6	1.0	12.0	1.0	13.5	ns
		$\bar{E}$ to nY; see Figure 8 ^[2]								
		$V_{CC} = 3.0 \text{ V}$ to 3.6 V								
		$C_L = 15 \text{ pF}$	-	5.9	13.2	1.0	15.5	1.0	16.5	ns
		$C_L = 50 \text{ pF}$	-	8.4	16.7	1.0	19.0	1.0	21.0	ns
		$V_{CC} = 4.5 \text{ V}$ to 5.5 V								
		$C_L = 15 \text{ pF}$	-	4.2	8.1	1.0	9.5	1.0	10.5	ns
		$C_L = 50 \text{ pF}$	-	6.0	10.1	1.0	11.5	1.0	13.0	ns

Table 7. Dynamic characteristics ...continuedGND = 0 V; For test circuit see [Figure 9](#).

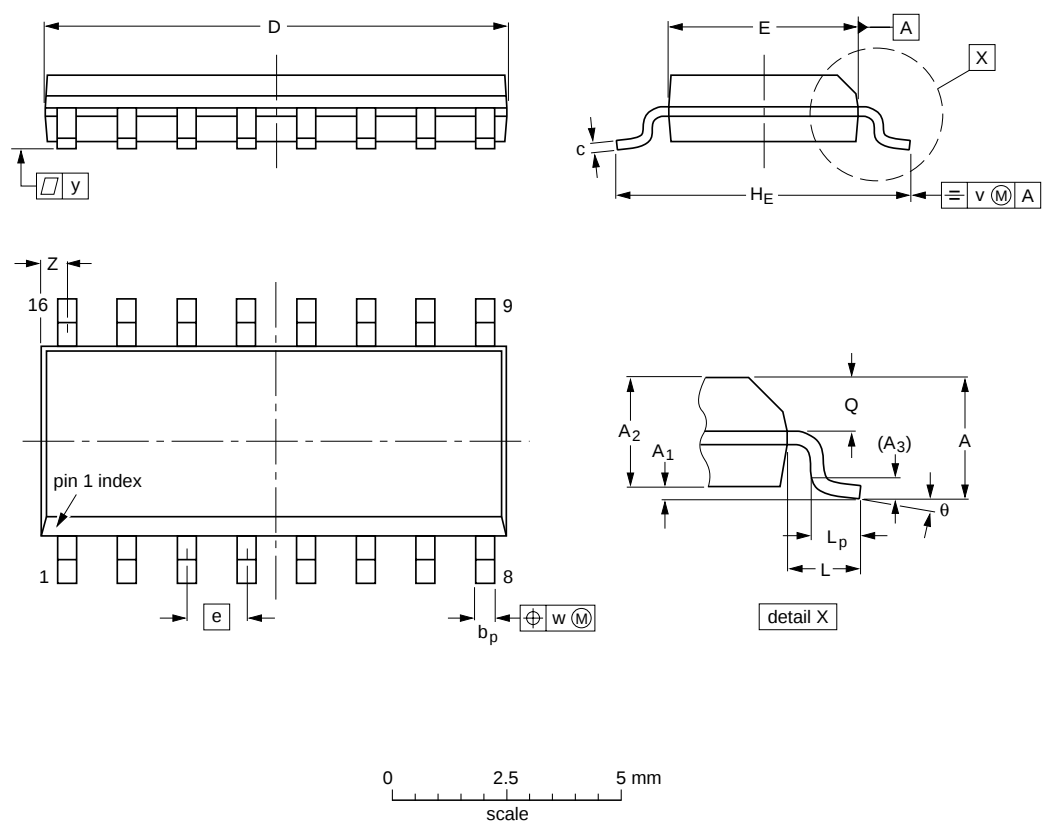
Symbol	Parameter	Conditions	25 °C			−40 °C to +85 °C		−40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	Min	Max	
C _{PD}	power dissipation capacitance	C _L = 50 pF; f _i = 1 MHz; [3] V _I = GND to V _{CC}								
		4 outputs switching via S	-	31	-	-	-	-	-	pF
		1 outputs switching via I	-	13	-	-	-	-	-	pF
For type 74AHCT157										
t _{pd}	propagation delay	nI0, nI1 to nY; see Figure 7 [2] V _{CC} = 4.5 V to 5.5 V								
		C _L = 15 pF	-	3.2	6.4	1.0	7.5	1.0	8.0	ns
		C _L = 50 pF	-	4.6	8.7	1.0	9.8	1.0	11.0	ns
		S to nY; see Figure 7 V _{CC} = 4.5 V to 5.5 V								
		C _L = 15 pF	-	3.7	8.6	1.0	10.0	1.0	11.0	ns
		C _L = 50 pF	-	5.2	10.4	1.0	12.0	1.0	13.0	ns
		$\overline{E}$ to nY; see Figure 8 [2] V _{CC} = 4.5 V to 5.5 V								
		C _L = 15 pF	-	4.7	8.1	1.0	9.5	1.0	10.5	ns
		C _L = 50 pF	-	6.7	10.6	1.0	12.0	1.0	13.5	ns
		C _{PD}	power dissipation capacitance	C _L = 50 pF; f _i = 1 MHz; [3] V _I = GND to V _{CC}						
4 outputs switching via S	-			41	-	-	-	-	-	pF
1 outputs switching via I	-			16	-	-	-	-	-	pF

[1] Typical values are measured at nominal supply voltage (V_{CC} = 3.3 V and V_{CC} = 5.0 V).[2] t_{pd} is the same as t_{PLH} and t_{PHL}.[3] C_{PD} is used to determine the dynamic power dissipation P_D (μW).
$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$$
 where:
f_i = input frequency in MHz;f_o = output frequency in MHz;C_L = output load capacitance in pF;V_{CC} = supply voltage in Volts.

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	Q	v	w	y	z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8° 0°
inches	0.069	0.010 0.004	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	

Note
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	
	IEC	JEDEC	JEITA			
SOT109-1	076E07	MS-012				

Fig 10. Package outline SOT109-1 (SO16)